Thyristor Semiconductor Device - Page 1 of 1



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	ure Material:
Metal	
	II Length:
0.265	inches
Termi	nal Length:
0.500	inches
Overa	II Diameter:
0.205	inches
Intern	al Configuration:
Junctio	on contact
Mount	ting Method:
Termir	nal
Termi	nal Circle Diameter:
0.095	inches
Featu	res Provided:
Herme	tically sealed case
Semic	conductor Material:
Silicon	
Voltag	e Rating In Volts Per Characteristic:
30.0 k	preakover voltage, dc
Curre	nt Rating Per Characteristic:
0.20 a	mperes source cutoff current
Maxin	num Operating Tempurature Per Measurement Point:
150.0	degrees celsius ambient air
Specia	al Features:
Junctio	on pattern arrangement: pnpn
Termi	nal Type And Quantity:
3 unin	sulated wire lead
Specif	fication Data:
80131	-release5472 professional/industrial association specification
Shelf	Life:
N/a	
Unit C	of Measure:
Demil	itarization:
No	
Fiig:	
A110a	0